

## **KENYA METHODIST UNIVERSITY**

# END OF 1<sup>ST</sup> TRIMESTER 2010 EXAMINATIONS

FACULTY	:	COMPUTING AND INFORMATICS
DEPARTMENT	:	COMPUTER INFORMATION SYSTEMS
UNIT CODE	:	CISY 204
UNIT TITLE	:	DIGITAL ELECTRONICS
TIME	:	2 HOURS

#### Instructions:

• Answer question 1 (compulsory) and any other 2 questions.

#### **Question 1 (compulsory)**

a)	Convert the following decimal numbers to binary and then the hexadecimal.

- i) 231 (3 mks) ii) 197 (3 mks)
- b) Design logic circuits using gates to realize these functions.
  - i)  $Y = (A + BC) (B + \overline{A}C)$  (3 mks) ii)  $Y = A\overline{B} + \overline{AB}$  (2 mks)
- c) Find two's compliment of the following binary numbers

i)	101110	(2 mks)
ii)	111011	(2 mks)

d)	i)	What is a multiplexer	?	(3 mks)		
	ii)	Construct a 32 x 1 mu	(6 mks)			
e)	i) ;;)	What are the advantages of dynamic RAMs over static RAMs?				(3 mks)
	11)	State timee applicatio		unters.	(5 1118)	
Questi	ion 2					
a)	i)	What is a flip-flop?	(1 mk)			
	ii)	Differentiate betweer	(2 mks)			
b)	Simplify the logic expressions using Boolean Algebra:					
	i)	$Y = A\overline{B} + \overline{AB}$	(3 mks)			
	ii)	A + B(A+B)	(3 mks)			

- c)i)Write the count sequence of a 3-bit down counter.(4 mks)ii)Design a ripple counter using flip-flop for this sequence.(4 mks)
- d) State three (3) types of digital to analog converters (DACs) (3 mks)

### Question 3

- a) i) What is a binary Adder? (2 mks)
  - ii) Design a circuit showing how the two signals A=1010 and B=0111 can be added by parallel full Adders. (7 mks)
- b) i) Design a 3-input OR gate. (2 mks)
  ii) Prepare a truth table for the above gate. (4 mks)
- c) State two applications of multiplexers. (2 mks)
- d) Differentiate between SRAM and DRAM. (3 mks)

#### Question 4

- a) Differentiate between:
  - i) RAM and ROM (4 mks)
  - ii) UVPROM and EEPROM (4 mks)
- b) State five applications of ROMs. (5 mks)
- c) What are the disadvantages of dynamic RAMs over static RAMs? (3 mks)
- d) Explain briefly 'cache memory'. (4 mks)